



TISP1070H3BJ THRU TISP1120H3BJ

DUAL FORWARD-CONDUCTING UNIDIRECTIONAL THYRISTOR OVERVOLTAGE PROTECTORS

TISP1xxxH3BJ Overvoltage Protector Series

Overvoltage Protection for Negative Rail SLICs

Dual High Current Protectors in a Space Efficient Package

- 2 x 100 A 10/1000 Current Rating
- SMB03 Package (3-pin Modified SMB/DO-214AA)
- 50 % Space Saving over Two SMBs

Ion-Implanted Breakdown Region

- Precise and Stable Voltage
- Low Voltage Overshoot under Surge

Device Name	V_{DRM} V	$V_{(BO)}$ V
TISP1070H3BJ	-58	-70
TISP1080H3BJ	-65	-80
TISP1095H3BJ	-75	-95
TISP1120H3BJ	-95	-120

Rated for International Surge Wave Shapes

Wave Shape	Standard	I_{PPSM} A
2/10	GR-1089-CORE	500
8/20	IEC 61000-4-5	300
10/160	TIA-968-A (FCC Part 68)	200
10/700	ITU-T K.20/21/45	150
10/560	TIA-968-A (FCC Part 68)	120
10/1000	GR-1089-CORE	100

Description

These dual unidirectional thyristor devices protect SLICs and ISDN power feeds in central office, access and customer premises equipment against overvoltages on the telecom line. Each protector section consists of a voltage-triggered unidirectional thyristor with an anti-parallel diode. In the negative polarity, the thyristor allows signal voltages, without clipping, up to the maximum off-state voltage value, V_{DRM} , see Figure 1. Voltages exceeding V_{DRM} are limited and will not exceed the breakdown voltage, $V_{(BO)}$, level. If sufficient current flows due to the overvoltage, the thyristor switches into a low-voltage on-state condition, which diverts the current from the overvoltage through the thyristor. When the diverted current falls below the holding current, I_H , level the thyristor switches off and restores normal system operation. Positive overvoltages are limited by the conduction of the anti-parallel diode.

The TISP1xxxH3BJ is available in four voltages and has a 100 A 10/1000 current rating. These protectors have been designed particularly for use in equipment that must meet the following standards and recommendations: GR-1089-CORE, TIA-968-A (replaces FCC Part 68), ITU-T K.20, K.21 and K.45. Housed in a SMB03 package (3-pin modified SMB/DO-214AA), these parts are space efficient to replace protection designs of 100 A 10/1000 or less which use multiple SMBs or a 6-pin SMT package.

How to Order

Device	Package	Carrier	For Standard Termination Finish Order As	For Lead Free Termination Finish Order As	Marking Code	Std. Qty.
TISP1xxxH3BJ	SMB03 (3-pin modified SMB/DO-214AA)	Embossed Tape Reeled	TISP1xxxH3BJR	TISP1xxxH3BJR-S	1xxxH3	3000

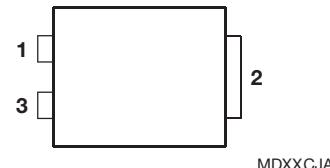
Insert xxx value corresponding to device name.

*RoHS Directive 2002/95/EC Jan 27 2003 including Annex JUNE 2003 - REVISED FEBRUARY 2005

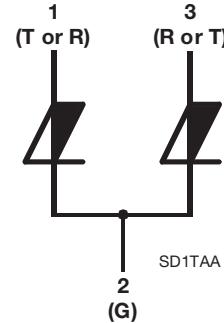
Specifications are subject to change without notice.

Customers should verify actual device performance in their specific applications.

SMB03 Package (Top View)



Device Symbol



..... UL Recognized Component

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Absolute Maximum Ratings, $T_A = 25^\circ\text{C}$ (Unless Otherwise Noted)

Rating	Symbol	Value	Unit
Repetitive peak off-state voltage, (Terminals 1-2 and 3-2) (see Note 1)	V_{DRM}	'1070	V
		'1080	
		'1095	
		'1120	
Non-repetitive peak on-state pulse current (see Notes 2 and 3)	I_{PPSM}	2x500	A
2/10 (Telcordia GR-1089-CORE, 2/10 voltage wave shape)		2x300	
8/20 (IEC 61000-4-5, combination wave generator, 1.2/50 voltage wave shape)		2x200	
10/160 (TIA-968-A (replaces FCC Part 68), 10/160 μs voltage wave shape)		2x150	
5/310 (ITU-T K.44, 10/700 μs voltage wave shape used in K.20/45/21)		2x150	
5/320 (TIA-968-A (replaces FCC Part 68), 9/720 μs voltage wave shape)		2x120	
10/560 (TIA-968-A (replaces FCC Part 68), 10/560 μs voltage wave shape)		2x100	
10/1000 (Telcordia GR-1089-CORE, 10/1000 voltage wave shape)			
Non-repetitive peak on-state current (see Notes 2 and 3)	I_{TSM}	2x30	A
50 Hz, 1 cycle		2x35	
60 Hz, 1 cycle		2x1.2	
1000 s 50 Hz/60 Hz a.c.			
Initial rate of rise of on-state current, Linear current ramp, Maximum ramp value < 50 A	di_T/dt	500	$\text{A}/\mu\text{s}$
Junction temperature	T_J	-40 to +150	$^\circ\text{C}$
Storage temperature range	T_{stg}	-65 to +150	$^\circ\text{C}$

NOTES: 1. At -40°C derate linearly to $0.93 \times V_{\text{DRM}}$ (25°C)
 2. Initially the device must be in thermal equilibrium with $T_J = 25^\circ\text{C}$.
 3. These non-repetitive rated currents are peak values of either polarity. The rated current values are applied to the terminals 1 and 3 simultaneously (in this case the terminal 2 return current will be the sum of the currents applied to the terminals 1 and 3). The surge may be repeated after the device returns to its initial conditions.

Electrical Characteristics for the 1 and 2 or the 3 and 2 Terminals, $T_A = 25^\circ\text{C}$ (Unless Otherwise Noted)

Parameter	Test Conditions	Min	Typ	Max	Unit
I_{DRM} Repetitive peak off-state current	$V_D = V_{\text{DRM}}$	$T_A = 25^\circ\text{C}$		-5	μA
$V_{(BO)}$ AC breakdown voltage	$dv/dt = -250 \text{ V/ms}$, $R_{\text{SOURCE}} = 300 \Omega$	'1070		-70	V
		'1080		-80	
		'1095		-95	
		'1120		-120	
$I_{(BO)}$ Breakover current	$dv/dt = -250 \text{ V/ms}$, $R_{\text{SOURCE}} = 300 \Omega$			-800	mA
I_H Holding current	$I_T = -5 \text{ A}$, $di/dt = +30 \text{ mA/ms}$	-150			mA
dv/dt Critical rate of rise of off-state voltage	Linear voltage ramp, Maximum ramp value < $0.85 \times V_{\text{DRM}}$	-5			$\text{kV}/\mu\text{s}$
I_D Off-state current	$V_D = -50 \text{ V}$	$T_A = 85^\circ\text{C}$		-10	μA
V_F Forward voltage	$I_F = +5 \text{ A}$, $t_W = 500 \mu\text{s}$			3	V

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Electrical Characteristics for the 1 and 2 or the 3 and 2 Terminals, $T_A = 25^\circ\text{C}$ (Unless Otherwise Noted)

Parameter	Test Conditions	Min	Typ	Max	Unit
C_{off} Off-state capacitance	$f = 1 \text{ MHz}, V_d = 1 \text{ V rms}, V_D = -2 \text{ V}$	'1070	161		
		'1080	152		
		'1095	139		
		'1120	116		
		'1070	58		
	$f = 1 \text{ MHz}, V_d = 1 \text{ V rms}, V_D = -50 \text{ V}$	'1080	55		
		'1095	50		
		'1120	42		
					pF

Thermal Characteristics

Parameter	Test Conditions	Min	Typ	Max	Unit
$R_{\theta JA}$ Junction to free air thermal resistance	EIA/JESD51-3 PCB, $T_A = 25^\circ\text{C}$, (see Note 4)			113	°C/W
	265 mm x 210 mm populated line card, 4-layer PCB, $I_T = I_{TSM(1000)}$, $T_A = 25^\circ\text{C}$		52		

NOTE 4: EIA/JESD51-2 environment and PCB have standard footprint dimensions connected with 5 A rated printed wiring track widths.

Parameter Measurement Information

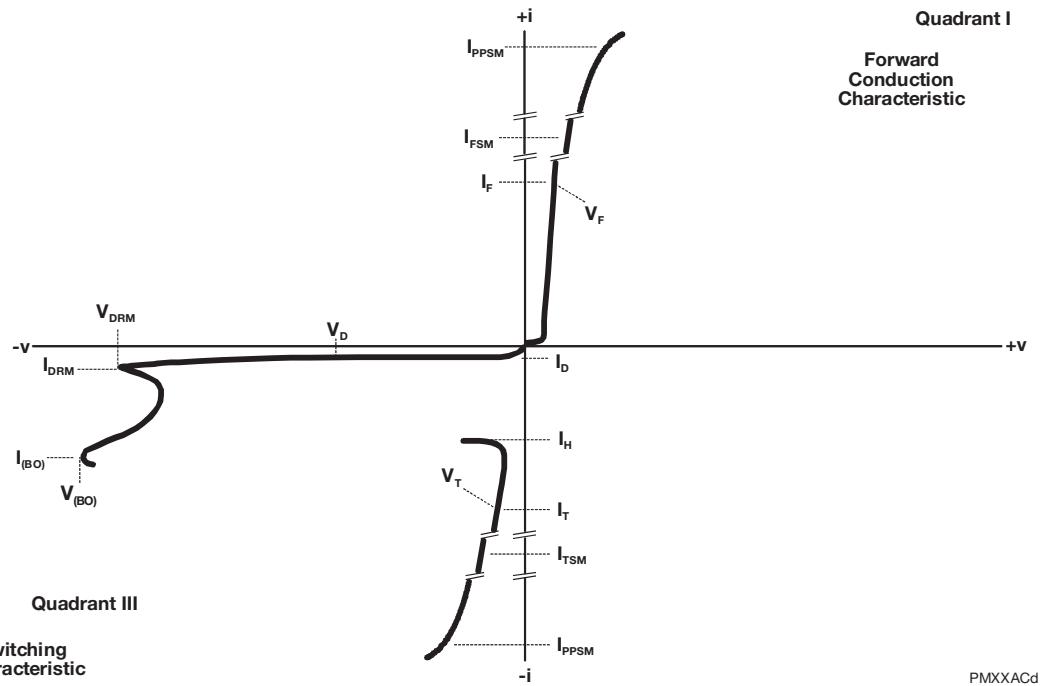


Figure 1. Voltage-Current Characteristic for Terminal Pairs 1-2 and 3-2
All Measurements are Referenced to Terminal 2

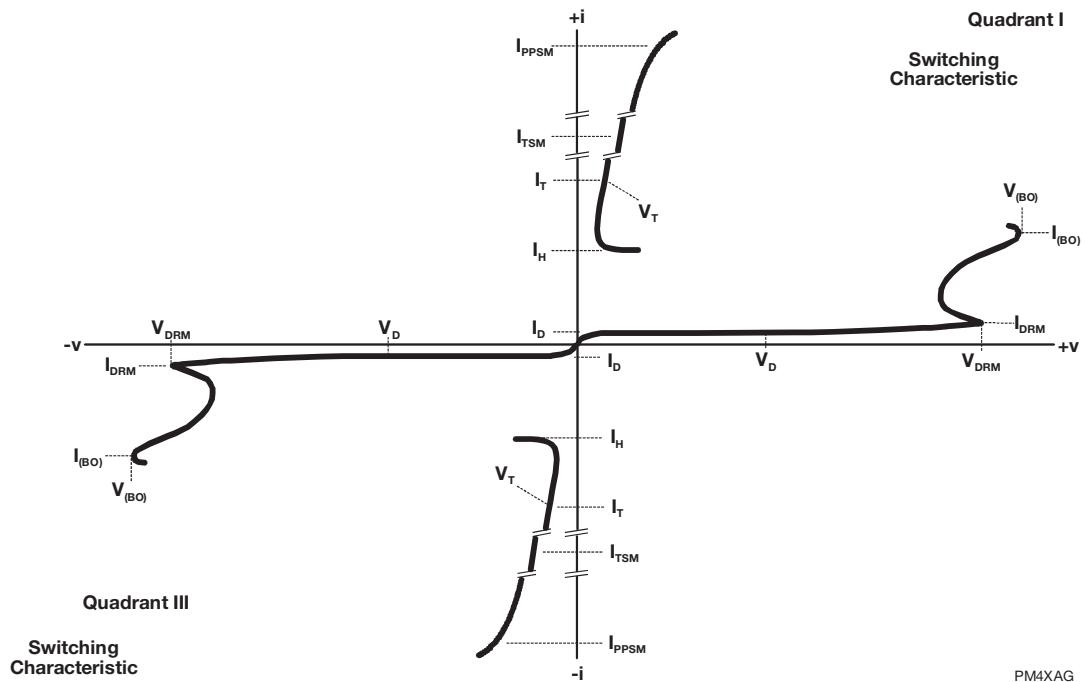


Figure 2. Voltage-Current Characteristic for Terminal Pair 1-3
All Measurements are Referenced to Terminal 3

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Typical Characteristics

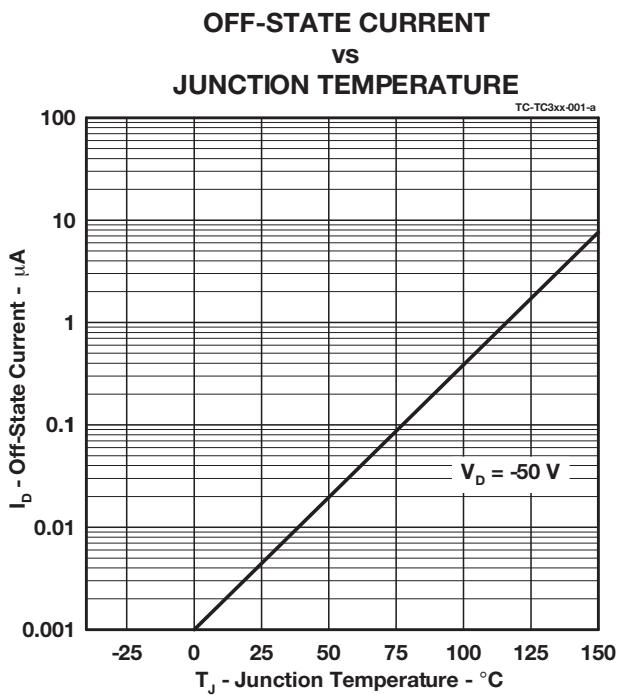


Figure 3.

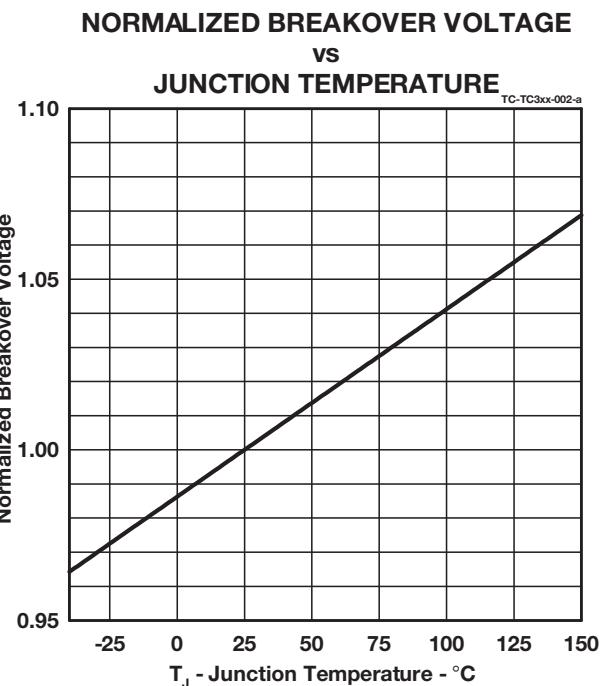


Figure 4.

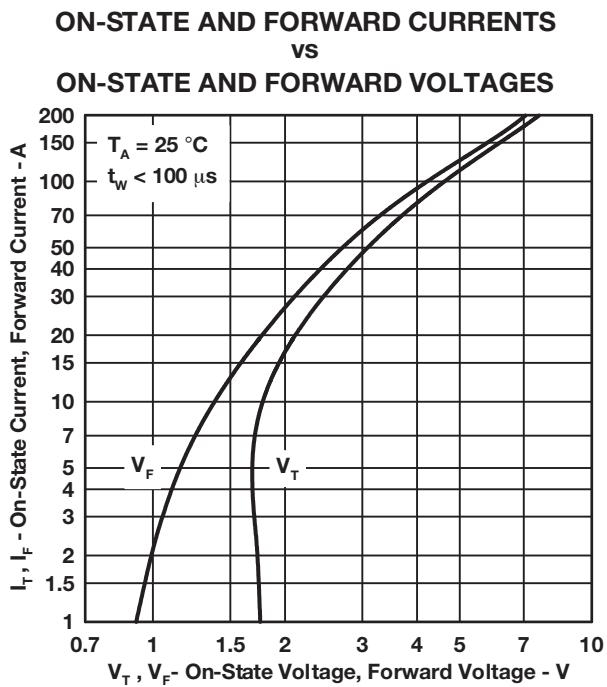


Figure 5.

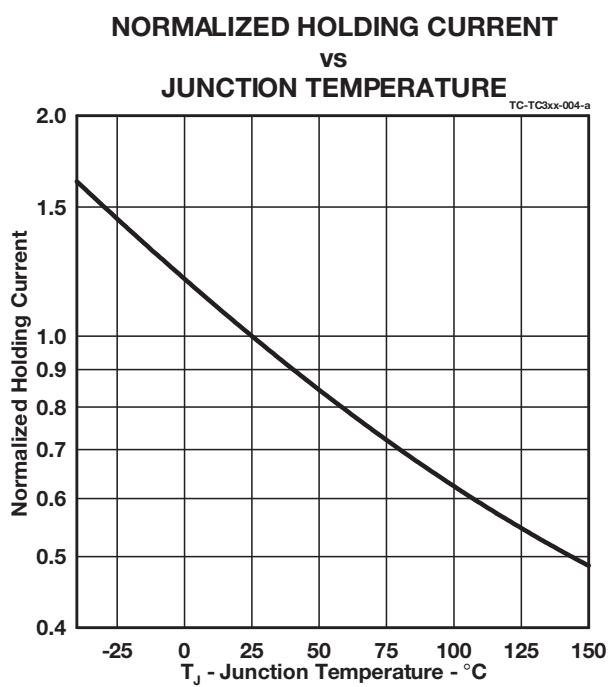


Figure 6.

Typical Characteristics (Continued)

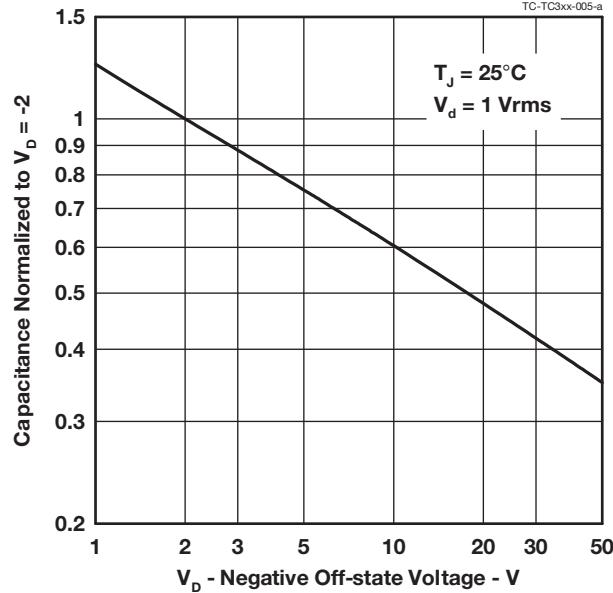
NORMALIZED CAPACITANCE
vs
OFF-STATE VOLTAGE

Figure 7.

Rating and Thermal Information

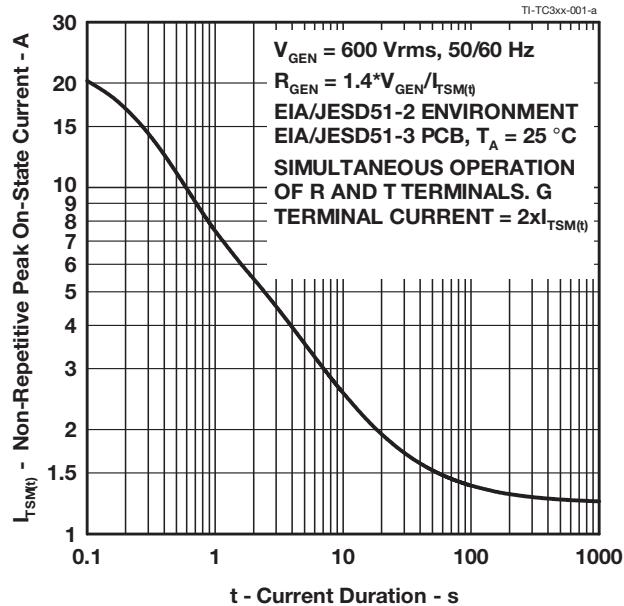
NON-REPETITIVE PEAK ON-STATE CURRENT
vs
CURRENT DURATION

Figure 8.

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